Lead-free Green

ZXPD4000DH

NPN DARLINGTON TRANSISTOR WITH RECTIFIER DIODE IN V-DFN3030-8 PACKAGE

Features

- Combination of 120V NPN Darlington Transistor and 120V Rectifier Diode
- High Current Gain: h_{FE} = 2000min @V_{CE} = 2V, I_C = 1A
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

Mechanical Data

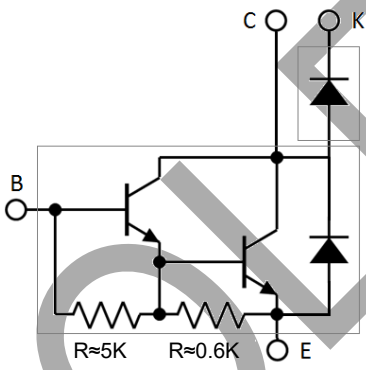
- Package: V-DFN3030-8
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.02 grams (Approximate)

Application

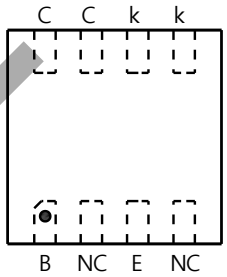
- Printer head drivers

V-DFN3030-8

Bottom View



Device Symbol



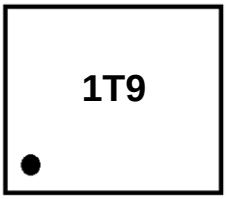
Top View
Pin-Out

Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
ZXPD4000DH-7	V-DFN3030-8	1T9	7	8	3000	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



1T9 = Product Type Marking Code

BJT Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	120	V
Collector-Emitter Voltage	V_{CEO}	120	V
Emitter-Base Voltage	V_{EBO}	8	V
Continuous Collector Current	I_C	2	A
Peak Collector Current	I_{CP}	3	A
Base Current	I_B	0.5	A

Diode Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	120	V
Average Current	$I_{F(AV)}$	1	A
Non-Repetitive Peak Forward Current (Surge Current), 1 Cycle (50Hz)	I_{FSM}	15	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	0.9	W
Power Dissipation (Note 6)	P_D	0.72	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	139	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	172	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	C

Notes:
5. For a device surface mounted on 25mm × 25mm × 1.6mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions.
6. Same as Note 5, except the device is mounted on minimum recommended pad layout.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

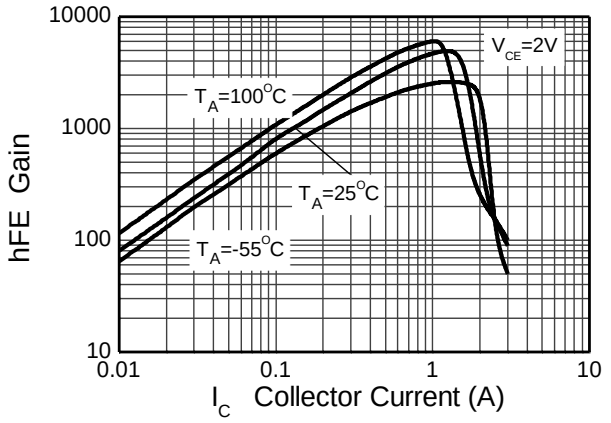
BJT Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

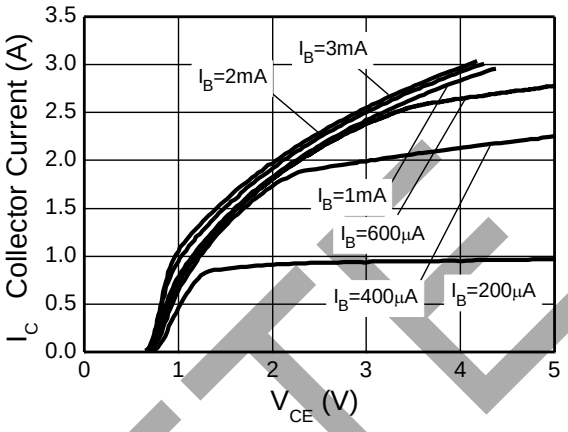
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector Cutoff Current	I_{CBO}	—	—	10	µA	V_{CB} = 120V, I_E = 0
Emitter Cutoff Current	I_{EBO}	1	—	2.67	mA	V_{EB} = 8V, I_C = 0
Collector-Emitter Breakdown Voltage	BV_{CEO}	120	—	—	V	I_C = 10mA, I_B = 0
DC Current Gain	h_{FE}	2000	—	9000	—	V_{CE} = 2V, I_C = 1A
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	1.5	V	I_C = 1A, I_B = 1mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	—	2	V	I_C = 1A, I_B = 1mA
Output Capacitance	C_{obo}	—	12	—	pF	V_{CB} = 10V, I_E = 0, f = 1MHz
Delay Time	t_d	—	0.34	—	µs	V_{CC} = 30V, R_L = 30Ω, I_{B1} = -I_{B2} = 1mA
Rise Time	t_r	—	1.8	—	µs	
Storage time	t_s	—	0.2	—	µs	
Fall Time	t_f	—	0.15	—	µs	

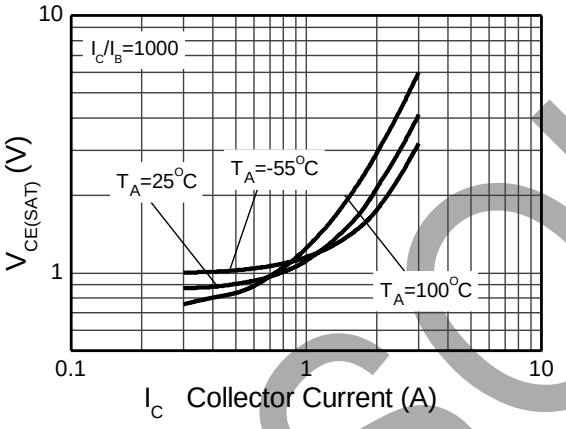
Diode Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

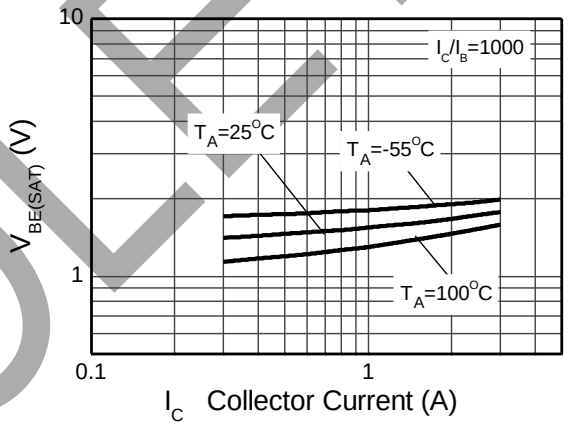
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Peak Forward Voltage	V_{FM}	—	—	0.98	V	I_{FM} = 1A
Reverse Leakage Current	I_R	—	—	10	µA	V_R = 120V
Reverse-Recovery Time	t_{RR}	—	300	450	ns	I_F = 1A, di/dt = -20A/µs
Forward-Recovery Time	t_{FR}	—	150	300	ns	I_F = 1A

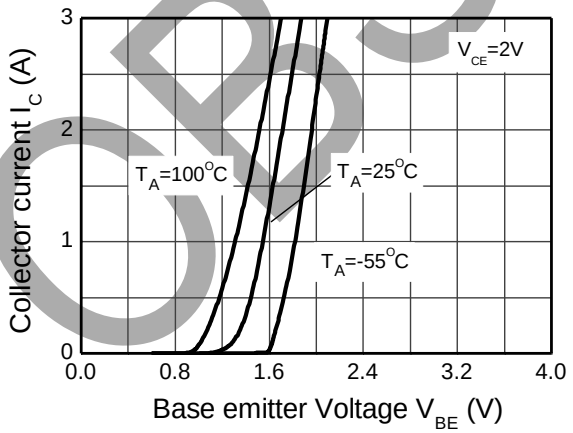
BJT Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



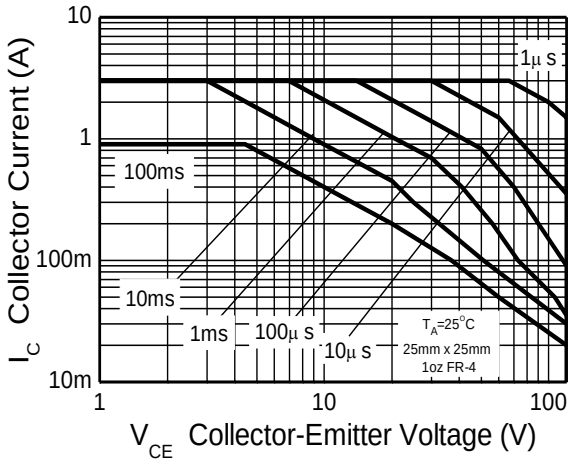




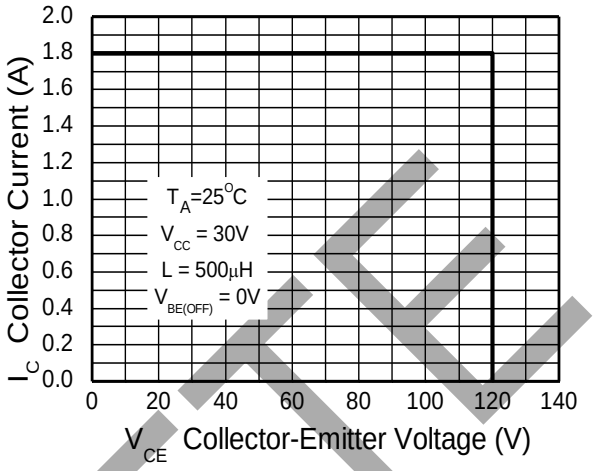




BJT Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) (continued)



Forward Bias Safe operating Area

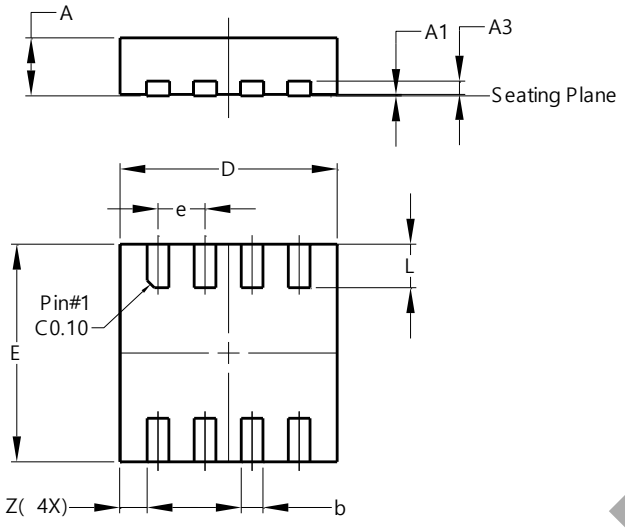


Reverse Bias Safe operating Area

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-8

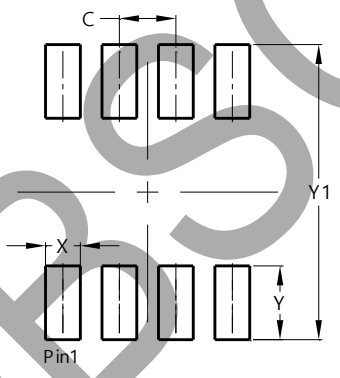


V-DFN3030-8			
Dim	**Min**	**Max**	**Typ**
A	0.75	0.85	0.80
A1	0.00	0.05	0.02
A3	-	-	0.203
b	0.25	0.35	0.30
D	2.95	3.05	3.00
E	2.95	3.05	3.00
e	-	-	0.65
L	0.55	0.65	0.60
Z	-	-	0.375
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-8



Dimensions	Value (in mm)
C	0.650
X	0.400
Y	0.850
Y1	3.400

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